Fibre Channel Coaxial Cable Driver and Loop Resiliency Circuit

Description

The MC10SX1189 is a differential receiver, differential transmitter specifically designed to drive coaxial cables. It incorporates the output cable drive capability of the MC10EL89 Coaxial Cable Driver with additional circuitry to multiplex the output cable drive source between the cable receiver or the local transmitter inputs. The multiplexer control circuitry is TTL compatible for ease of operation.

The MC10SX1189 is useful as a bypass element for Fibre Channel-Arbitrated Loop (FC-AL) or Serial Storage Architecture (SSA) applications, to create loop style interconnects with fault tolerant, active switches at each device node. This device is particularly useful for back panel applications where small size is desirable.

The EL89 style drive circuitry produces swings twice as large as a standard PECL output. When driving a coaxial cable, proper termination is required at both ends of the line to minimize reflections. The 1.6 V output swings allow for proper termination at both ends of the cable, while maintaining the required swing at the receiving end of the cable. Because of the larger output swings, the QT, $\overline{\rm QT}$ outputs are terminated into the thevenin equivalent of 50 Ω to V_{CC} – 3.0 V instead of 50 Ω to V_{CC} – 2.0 V.

Features

- 425 ps Propagation Delay
- 1.6 V Output Swing on the Cable Driving Output
- Operation Range:
 - $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$
- 75 kΩ Internal Input Pull Down Resistors
- >1000 V ESD Protection
- Transistor Count = 102
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant



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FIBRE CHANNEL COAXIAL CABLE DRIVER AND LOOP RESILIENCY CIRCUIT



SOIC-16 CASE 751B-05

MARKING DIAGRAM*



10SX1189 = Specific Device Code A = Assembly Location

WL = Wafer Lot
 Y = Year
 WW = Work Week
 G = Pb-Free Package

(Note: Microdot may be in either location)

*For additional marking information, refer to Application Note <u>AND8002/D</u>.

ORDERING INFORMATION

| Device | Package | Shipping |
|--------------|----------------------|---------------|
| MC10SX1189DG | SOIC-16 (Pb-Free) | 48 Units/Tube |

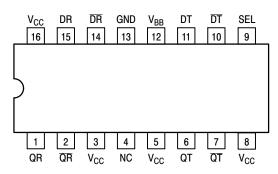


Figure 1. Pinout: SOIC-16 (Top View)

TRUTH TABLE

| SEL | Function |
|--------|---|
| L H | $\begin{array}{c} DR \to QT \\ DT \to QT \end{array}$ |

PIN NAMES

| Pins | Function |
|----------|---|
| DR/DR | Differential Input from Receive Cable |
| QR/QR | Buffered Differential Output from Receive Cable |
| DT/DT | Differential Input to Transmit Cable |
| QT/QT | Buffered Differential Output to |
| | Transmit Cable |
| SEL | Multiplexer Control Signal (TTL) |
| V_{CC} | Positive Power Supply |
| GND | Ground |
| V_{BB} | Reference Voltage Output |

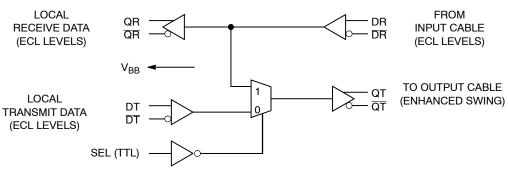


Figure 2. LOGIC DIAGRAM

Table 1. ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|------------------|--|-------------|------|
| V _{CC} | Power Supply Voltage (Referenced to GND) | 0 to +7.0 | Vdc |
| V _{IN} | Input Voltage (Referenced to GND) | 0 to +6.0 | Vdc |
| l _{OUT} | Output Current Continuous Surge | 50 100 | mA |
| T _A | Operating Temperature Range | -40 to +85 | °C |
| T _{STG} | Storage Temperature Range | -50 to +150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 2. DC CHARACTERISTICS ($V_{CC} = 5.0 \text{ V}, V_{EE} = 0 \text{ V}$)

| | | | -40°C |)°C 25°C | | | | | | | |
|-----------------|---|------|-------|----------|------|------|------|------|------|------|------|
| Symbol | Characteristic | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| V _{OH} | Output Voltage High (QR, QR) V _{CC} = 5.0 V, GND = 0 V (Notes 1, 2) | 3.92 | 4.05 | 4.22 | 3.97 | 4.11 | 4.27 | 4.00 | 4.16 | 4.30 | V |
| V _{OL} | Output Voltage Low (QR, QR) V _{CC} = 5.0 V, GND = 0 V (Notes 1, 2) | 3.05 | 3.23 | 3.35 | 3.07 | 3.24 | 3.37 | 3.10 | 3.25 | 3.41 | V |
| V _{OH} | Output Voltage High (QT,QT) V _{CC} = 5.0 V, GND = 0 V (Notes 1, 3) | 3.83 | 3.95 | 4.10 | 3.88 | 4.02 | 4.15 | 3.90 | 4.09 | 4.17 | V |
| V _{OL} | Output Voltage Low (QT,QT) V _{CC} = 5.0 V, GND = 0 V (Notes 1, 3) | 1.90 | 2.33 | 2.50 | 1.85 | 2.26 | 2.45 | 1.85 | 2.23 | 2.45 | ٧ |
| I _{CC} | Quiescent Supply Current (Note 4) | 20 | 25 | 42 | 23 | 27 | 47 | 25 | 28 | 47 | mA |
| V _{IH} | Input Voltage High (DR, DR & DT, DT) V _{CC} = 5.0 V, GND = 0 V (Note 1) | 3.77 | | 4.11 | 3.87 | | 4.19 | 3.94 | | 4.28 | V |
| V _{IL} | Input Voltage Low (DR, DR & DT, DT) V _{CC} = 5.0 V, GND = 0 V (Note 1) | 3.05 | | 3.50 | 3.05 | | 3.52 | 3.05 | | 3.56 | ٧ |
| V _{IH} | Input Voltage High SEL | 2.0 | | | 2.0 | | | 2.0 | | | V |
| V_{IL} | Input Voltage Low SEL | | | 0.8 | | | 0.8 | | | 0.8 | V |
| V _{BB} | Output Reference Voltage V _{CC} = 5.0 V, GND = 0 V (Note 1) | 3.57 | 3.63 | 3.70 | 3.65 | 3.70 | 3.75 | 3.69 | 3.75 | 3.81 | V |
| I _{IH} | Input HIGH Current | | | 150 | | | 150 | | | 150 | μΑ |
| I _{IL} | Input LOW Current | 0.5 | | | 0.5 | | | 0.5 | | | μΑ |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 1. Values will track 1:1 with the V_{CC} supply. V_{EE} can vary +0.5 V to -0.5 V. 2. Outputs loaded with 50 Ω to V_{CC} 2.0 V. 3. Outputs loaded with 50 Ω to V_{CC} 3.0 V. 4. Outputs open circuited.

Table 3. AC CHARACTERISTICS (V_{CC} = 4.5 V to 5.5 V) (Note 1)

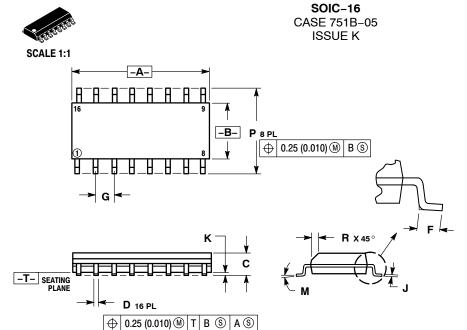
| | | | -40°C 0 to 85°C | | | | | | |
|--|---|--|--|--|--|--|--|------|--------------------------|
| Symbol | Characteristic | Min | Тур | Max | Min | Тур | Max | Unit | Condition |
| t _{PLH} , t _{PHL} | Propagation Delay to Output $DR \rightarrow QR$ (Diff) (SE) $DR \rightarrow QT$ (Diff) (SE) $DT \rightarrow QT$ (Diff) (SE) | 175 150 250 225 225 200 | 300 300 425 425 400 400 | 450 500 650 700 650 725 | 225 175 300 250 275 225 | 325 325 450 450 425 425 | 500 550 650 700 650 725 | ps | Note 2 Note 3 |
| | Propagation Delay SEL → QT,QT | 450 | 600 | 850 | 500 | 650 | 800 | | 1.5V to 50% Pt |
| t _r , t _f | Rise TimeQR,QR Fall Time | 100 100 | 275 275 | 400 400 | 125 125 | 275 275 | 400 400 | ps | 20% to 80% 80% to 20% |
| t _r , t _f | Rise TimeQT,QT Fall Time | 150 150 | 300 300 | 550 550 | 150 150 | 300 300 | 550 550 | ps | 20% to 80% 80% to 20% |
| t _{skew} | Within Device Skew | | 15 | | | 15 | | ps | Note 4 |
| V_{PP} | Minimum Input Swing | 200 | | 1000 | 200 | | 1000 | mV | Note 5 |
| V _{CMR} | Common Mode Range | 3.00 | | 4.35 | 3.00 | | 4.35 | V | Note 6 |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 1. V_{EE} can vary +0.5 V to -0.5 V.
- The differential propagation delay is defined as the delay from the crossing points of the differential input signals to the crossing point of the differential output signals.
- 3. The single-ended propagation delay is defined as the delay from the 50% point of the input signal to the 50% point of the output signal.
- 4. Duty cycle skew is the difference between t_{PLH} and t_{PHL} propagation delay through a device.
- 5. Minimum input swing for which AC parameters are guaranteed.
- The CMR range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between V_{PP Min} and 1.0 V.

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MECHANICAL CASE OUTLINE



DATE 29 DEC 2006

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI
- THE NOTION AND TOLETANOING FER ANSI'Y 14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
- PHOI HUSION.

 MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.

 DIMENSION D DOES NOT INCLUDE DAMBAR
 PROTRUSION. ALLOWABLE DAMBAR PROTRUSION

 SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D

 DIMENSION AT MAXIMUM MATERIAL CONDITION.

| | MILLIN | IETERS | INC | HES | |
|-----|--------|--------|-----------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 9.80 | 10.00 | 0.386 | 0.393 | |
| В | 3.80 | 4.00 | 0.150 | 0.157 | |
| C | 1.35 | 1.75 | 0.054 | 0.068 | |
| D | 0.35 | 0.49 | 0.014 | 0.019 | |
| F | 0.40 | 1.25 | 0.016 | 0.049 | |
| G | 1.27 | BSC | 0.050 BSC | | |
| 7 | 0.19 | 0.25 | 0.008 | 0.009 | |
| K | 0.10 | 0.25 | 0.004 | 0.009 | |
| M | 0° | 7° | 0° | 7° | |
| Р | 5.80 | 6.20 | 0.229 | 0.244 | |
| R | 0.25 | 0.50 | 0.010 | 0.019 | |

| STYLE 1: | | STYLE 2: | | STYLE 3: | | STYLE 4: | | | |
|----------|---------------|----------|---------------|----------|----------------------|----------|----------------|----------------|-------------------------|
| PIN 1. | | PIN 1. | | PIN 1. | COLLECTOR, DYE #1 | PIN 1. | COLLECTOR, DYE | #1 | |
| 2. | | | ANODE | 2. | BASE, #1 | 2. | COLLECTOR, #1 | | |
| 3. | EMITTER | 3. | NO CONNECTION | 3. | EMITTER, #1 | 3. | COLLECTOR, #2 | | |
| 4. | NO CONNECTION | 4. | CATHODE | 4. | COLLECTOR, #1 | 4. | COLLECTOR, #2 | | |
| 5. | EMITTER | 5. | CATHODE | 5. | COLLECTOR, #2 | 5. | COLLECTOR, #3 | | |
| 6. | BASE | 6. | NO CONNECTION | 6. | BASE, #2 | 6. | COLLECTOR, #3 | | |
| 7. | COLLECTOR | 7. | ANODE | 7. | EMITTER, #2 | 7. | COLLECTOR, #4 | | |
| 8. | COLLECTOR | | | 8. | COLLECTOR, #2 | 8. | COLLECTOR, #4 | | |
| 9. | BASE | | CATHODE | 9. | COLLECTOR, #3 | 9. | BASE, #4 | | |
| 10. | EMITTER | 10. | ANODE | 10. | BASE, #3 | 10. | EMITTER, #4 | | |
| 11. | NO CONNECTION | 11. | | 11. | EMITTER, #3 | 11. | BASE, #3 | | |
| 12. | EMITTER | | CATHODE | 12. | | 12. | | | |
| 13. | BASE | | CATHODE | 13. | COLLECTOR, #4 | 13. | BASE, #2 | SOI DEDING | FOOTPRINT |
| 14. | | | NO CONNECTION | 14. | BASE, #4 | 14. | EMITTER, #2 | SOLDERING | FOOTFRINT |
| 15. | EMITTER | | ANODE | 15. | EMITTER, #4 | 15. | BASE, #1 | 8 | ЗX |
| 16. | COLLECTOR | 16. | CATHODE | 16. | COLLECTOR, #4 | 16. | EMITTER, #1 | - 6 | .40 ──── |
| | | | | | | | | - | - |
| STYLE 5: | | STYLE 6: | | STYLE 7: | | | | | 16X 1.12 < |
| PIN 1. | DRAIN, DYE #1 | | CATHODE | PIN 1. | SOURCE N-CH | | | | , |
| 2. | DRAIN. #1 | | CATHODE | 2. | COMMON DRAIN (OUTPUT |) | | . 🗀 1 | 16 |
| 3. | DRAIN, #2 | | CATHODE | 3. | COMMON DRAIN (OUTPUT | | | , | '' |
| 4. | DRAIN, #2 | 4. | CATHODE | 4. | GATE P-CH | , | | | |
| 5. | DRAIN, #3 | 5. | CATHODE | 5. | COMMON DRAIN (OUTPUT |) | 16 | 5X T | |
| 6. | DRAIN, #3 | 6. | CATHODE | 6. | COMMON DRAIN (OUTPUT | | 0.5 | | ' <u> </u> |
| 7. | DRAIN, #4 | 7. | CATHODE | 7. | COMMON DRAIN (OUTPUT | | 0.0 | | |
| 8. | DRAIN, #4 | 8. | CATHODE | 8. | SOURCE P-CH | , | | | |
| 9. | GATE, #4 | 9. | ANODE | 9. | SOURCE P-CH | | | | |
| 10. | SOURCE, #4 | 10. | ANODE | 10. | COMMON DRAIN (OUTPUT |) | | | |
| 11. | GATE, #3 | 11. | ANODE | 11. | COMMON DRAIN (OUTPUT | | | | |
| 12. | SOURCE, #3 | 12. | ANODE | 12. | COMMON DRAIN (OUTPUT | | | | |
| 13. | GATE, #2 | 13. | ANODE | 13. | GATE N-CH | , | | | ¦ |
| 14. | SOURCE, #2 | 14. | ANODE | 14. | COMMON DRAIN (OUTPUT |) | | | ↓ PITCH |
| 15. | GATE, #1 | 15. | ANODE | 15. | COMMON DRAIN (OUTPUT | | | | <u>+-+</u> |
| 16. | SOURCE, #1 | 16. | ANODE | 16. | SOURCE N-CH | , | | | |
| | • | | | | | | | □ ₈ | 9 + - + - |
| | | | | | | | | • | , |
| | | | | | | | | | BINENIOLONIO MILLINETTE |
| | | | | | | | | | DIMENSIONS: MILLIMETERS |

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| DESCRIPTION: | SOIC-16 | | PAGE 1 OF 1 | | | |

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